Scope

The present specifications shall apply to a 3 phase brushless motor driver IC, SI-6635M. The present specifications shall apply to SI-6635M which is performed RoHS instructions. The present specifications, which shows in Japanese and English, shall be prior to Japanese.

Outline

Туре	Monolithic integrated circuit
Structure	Plastic molded (transfer mold)
Applications	3 phase brushless motor driver (Sinusoidal Current Control)

Absolute maximum ratings

			C Y	
e maximum ratings			062	
Items	Symbol	Condition	Limit	Unit
Power supply voltage	V_{BB}		-0.3~38	V
Output voltage ^{**1}	V _{OUT}		$-0.5 \sim V_{BB}$	V
Output current ^{**2}	I _{OUT(Ave)}		±2	А
Output current	I _{OUT(Peak)}	tw<500msec/Duty<10%	±4	А
Open drain output sink current	I _{OD}	FG/FLAG	10	mA
Logic input voltage	V _{IN(Logic)}		-0.3~5.5	V
Logic output voltage	V _{OUT(Logic)}	FG/FLAG	-0.3~5.5	V
Analog input voltage	V _{IN(Analog)}		-0.3~6	V
Sense voltage	V _{SENSE}		±0.5	V
Package power dissipation	PD	SK evaluation board	4.1	W
Maximum junction temperature	T_J		150	°C
Storage temperature	T _{stg}		-40~150	°C
Ambient temperature	T _A		-20~85	°C

Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of conditions, do not exceed the specified junction temperature (T_i) .

※1 Output voltage can not be over 38V.

[★]2 Peak current is guaranteed by design.

Electrical characteristics

Recommended Operating Range

Thomas	Chal	Limit		T I a i 4	Dement	
Items	Symbol	Min	Max	Unit	Remark	
Power supply voltage	V_{BB}	10	30	V	In normal operation	
Logic input voltage	$V_{\rm IN(Logic)}$	0	5.25	V		
Analog input voltage	V _{IN} (Analog)	0	5.25	V		
CLK input range	$\mathbf{F}_{\mathrm{CLK}}$	9.5	20	MHz		
Sense voltage	Vsen	-0.5	0.5	V		
Package temperature	$T_{\rm C}$	-20	105	°C		
Ambient	TA	-20	85	°C	Ġ	
temperature	IA	-20	00	C		

Note) Especially, care should be taken with output current on condition over recommended range and below absolute max rating. In this case, enough evaluation is needed with thermal design data below and application note to avoid the device being over absolute max rating for other item.

Electrical Characteristic $(T_a=25^{\circ}C, V_{BB}=24V, Unless Otherwise Noted.)$

Item	Sumah al		Limit		Unit	Condition
Item	Symbol	MIN	TYP	MAX	Unit	Condition
Output Drivers						
VBB voltage range	V _{BB}	10	-	V _{BBOV}	V	In normal operation
		5	-	25	mA	Opration state
Main power supply current	I _{BB}	3	-	25	mA	Non-operation state with charge pomp OFF, output OFF
Output ON resistance	Ron	0.1	0.2	0.3	Ω	Iout=2A
MOSFET diode forward volatge	VF	0.3	1.15	2.0	V	Iout=2A
Control Logic						
VDD voltage range	V _{DD}	3.0	3.3	3.5	V	In operation
La sia inanyati ya kasa	V _{IN(0)}	-	-	$V_{DD} \times 0.3$	V	
Logic input voltage	V _{IN(1)}	V _{DD} × 0.7	-	-	V	Ste
	I _{IN(0)}	-10	0	10	μA	V _{IN(0)} , V _{IN} =0V
Logic input current	T	-10	0	10	μA	$V_{IN(1)}$, V_{IN} =5.5V, SDA/SCL
	I _{IN(1)}	45	-	145	μA	V _{IN(1)} , V _{IN} =5.5V, ADRS1/ADRS2/BRKn
Internal PWM						
Sen pin input current	I _{Sen}	-10	0	10	μA	V _{Sen} =0~0.5V

t_{LPFSen} Current sensing filter time Typ data is for reference only. •

Sense voltage

the species of the sp Negative current is defined as coming out of the specified pin.

V_{Ser}

0.21

0.5

0.25

2

0.29

4

 \mathcal{N}

μs

With VREF=0.25V

Guaranteed by design

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Electrical Characteristic(continued) ($T_a=25^{\circ}C, V_{BB}=24V$, Unless Otherwise Noted.)

		- a	Limit	241, 0		
Item	Symbol	MIN	TYP	MAX	Unit	Condition
Protection				111/07		
Flag output saturation voltage	V _{FI(ON)}	0.08	0.45	0.7	V	I _{FG} =2mA
Flag output pin ON current	I _{FI(ON)}	5	7.5	25	mA	V _{FI} =2V
Flag output leak current	I _{FI(OFF)}	-1	0	50	μA	V _{FG} =5.5V
	V _{OCPLS}	0.7	1.2	2	V	LowSideMOSFET sensing (OUT-GND)
OCP sensing volatge	V _{OCPHS}	0.3	0.8	1.8	V	HighSideMOSFETsensing (VBB-GND)
VBB overvoltage protection threshold voltage	V _{BBOV}	32	35	38	V	In V _{BB} voltage rising
VBB overvoltageprotection hysteresis	$V_{BBOVhys}$	1.4	2	5.1	V	5
Thermal protection <pre>operating temperature</pre>	T _{JTSD}	-	165	-	°C	In temperature rising Guaranteed by desigr
Thermal protection hysteresis	T _{JTSDhys}	-	50	-	°C	S
VDD UVLO releasing voltage	V _{DDUV}	2.55	3.0	3.3	V	In V _{DD} voltage rising
VDD UVLO hysteresis	V_{DDUVhys}	0.15	0.25	0.35	V	
VBB UVLO releasing voltage	V _{BBUV}	6.5	9	9.75	V	In V _{BB} voltage rising
VBB UVLO hysteresis	$V_{BBUVhys}$	0.15	0.3	0.45	V	
FG						
FG output saturation voltage	$V_{FG(sat)}$	0.08	0.45	0.7	V	I _{FG} =2mA
FG output pin ON current	I _{FI(ON)}	5	7.5	25	VY	V _{FI} =2V
FG output leak current	I _{FGlkg}	-1	0	50	μΑ	V _{FG} =5.5V
Hall Logic				X		
Hall input current	I _{HALL}	-2	-0.1	2	μΑ	V _{IN} =0.2~3.5V
Common mode input voltage	V _{CMR}	0.2	5	4	V	
AC input voltage range	V_{HALL}	60		-	mV_{p-p}	
Hysteresis	V _{HYS}	20	40	V_{HALL}	mV	
Pulse removal filter	t _{pulse}	0.9	2	4	μs	
Hall input thresh voltage	V _{HIC(1)}	2.3	2.5	2.8	V	In applied voltage rising/ Hall IC input
Hall input hysteresis	V _{HIC(1)HYS}	20	40	60	mV	Hall IC input
FG amplifier						
FG input bias current	I _{BFG}	-1	0	1	μΑ	
FG input offset voltage	V _{OSFG}	-60	_	60	mV	
FGO output leak current	I _{OH}	-110	_	10	μΑ	
FGO output L voltage	V _{OL}	0.05	-	0.6	V	I=10uA
FG amplifier bias voltage	V _{BFG}	2.2	2.5	2.8	V	
FG comparator hysteresis	V_{FGhys}	20	70	150	mV	

Typ data is for reference only.
Negative current is defined as coming out of the specified pin.

SSJ-

Serial Interface

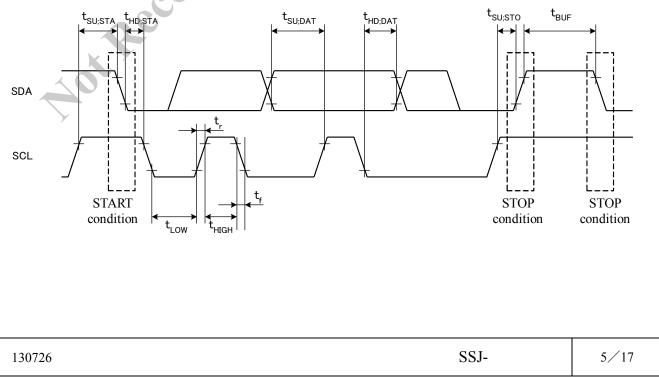
Electrical Characteristic(continued) ($T_a=25^{\circ}C, V_{BB}=24V$, Unless Otherwise Noted.)

	a 1 1	a		Rati	ngs	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
SCL Clock Frequency	f _{sc∟}				400	kHz
Start Condition Hold Time	t _{HD;STA}		0.6			μs
Start Condition Set Up Time	t _{su;sta}		0.6		Ġ	μs
SCL Low Time	t _{LOW}		1.3			μs
SCL High Time	t _{HIGH}		0.6		2	μs
SDA Hold Time	t _{hd;dat}		0	27	900	ns
SDA Set Up Time	t _{su;dat}		100			ns
Rising Time of SCL and SDA	t _r		7		300	ns
Falling Time of SCL and SDA	t _f				300	ns
Stop Condition Set Up Time	t _{su;sto}		0.6			μs
Bus Free Time between Stop and Start Condition	t _{BUF}	3	1.3			μs

% All threshold voltage referred to $V_{I\!H}(Min.)$ and $V_{I\!L}(Max.)$ level.

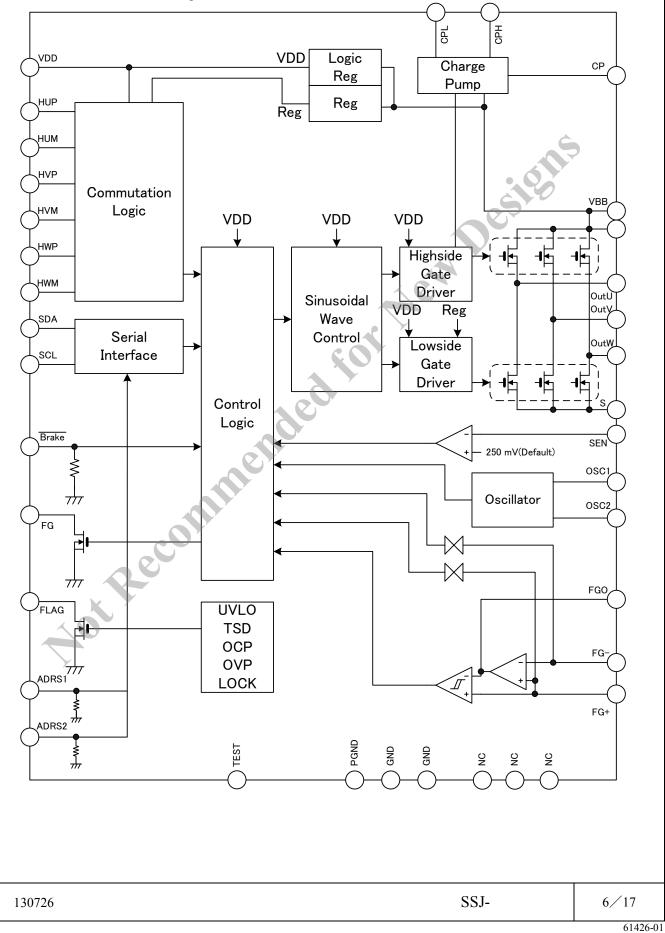
*There are design guarantee values.

Serial Timing



Block diagram (Connection diagram)

Internal functional block diagram

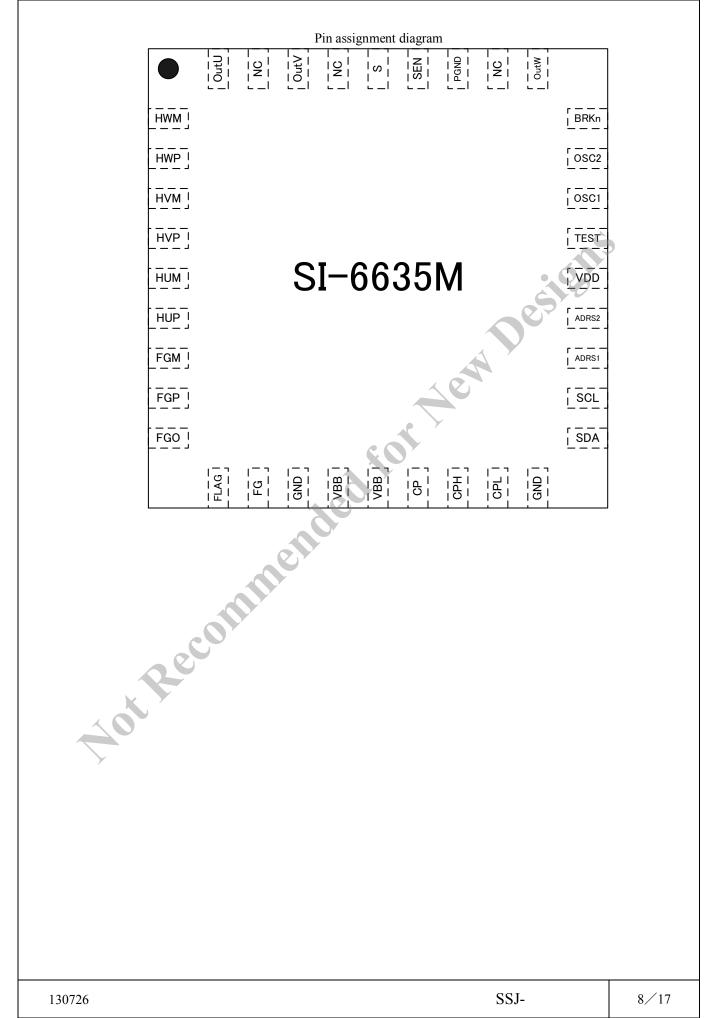


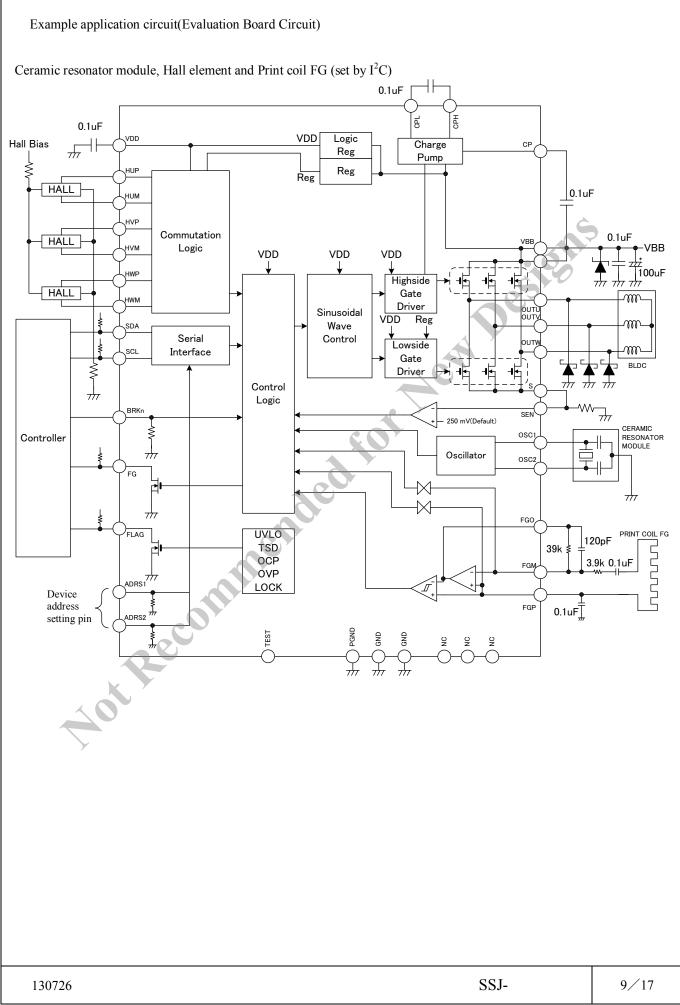
Pin Assignment (Terminal Functions)

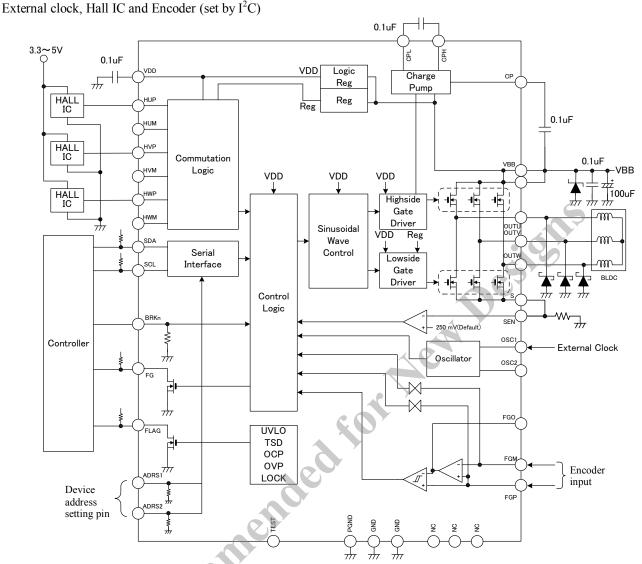
Pin Assign	ment (Termi	nal Functions)
1	HWM	Hall input W-
2	HWP	Hall input W+
3	HVM	Hall input V-
4	HVP	Hall input V+
5	HUM	Hall input U-
6	HUP	Hall input U+
7	FGM	Pattern FG input (-)/ Encoder input
8	FGP	Pattern FG input (+)/ Encoder input
ç	FGO	Pattern FG feedback
10	FLAG	Output for protection detected
11	FG	FG signal output/ Error output for designated speed
12	GND	Ground
13	VBB	Motor power supply
14	VBB	Motor power supply
15	CP	Reservoir pin for charge pump
16	CPH	Reservoir pin for charge pump (High)
17	CPL	Reservoir pin for charge pump (Low)
18	GND	Ground
19	SDA	Serial interface (data)
20	SCL	Serial interface (clock)
21	ADRS1	Device address setting(most significant bit)
22	ADRS2	Device address setting (least significant bit)
23	VDD	Ceramic capacitor connection for internal regulator
24	TEST	for test
25	OSC1	for ceramic oscillator connection/External clock input
26	OSC2	for ceramic oscillator connection
27	BRKn	Brake input
28	OUTW	Output for W phase
29	N.C.	No connection
30	PGND	Power ground
31	SEN	Current sensing input
32	S	Source pin
33	N.C.	No connection
34	OUTV	Output for V phase
35	N.C.	No connection
36	OUTU	Output for U phase

* Both VBB pins should be connected to VBB line on PCB.

* GND pins and PGND pin should be connected to GND line on PCB.







*1 : The capacitance on VBB or VDD is used as close to the device as possible.

2: Care should be taken for power dissipation for SEN/S resistance.

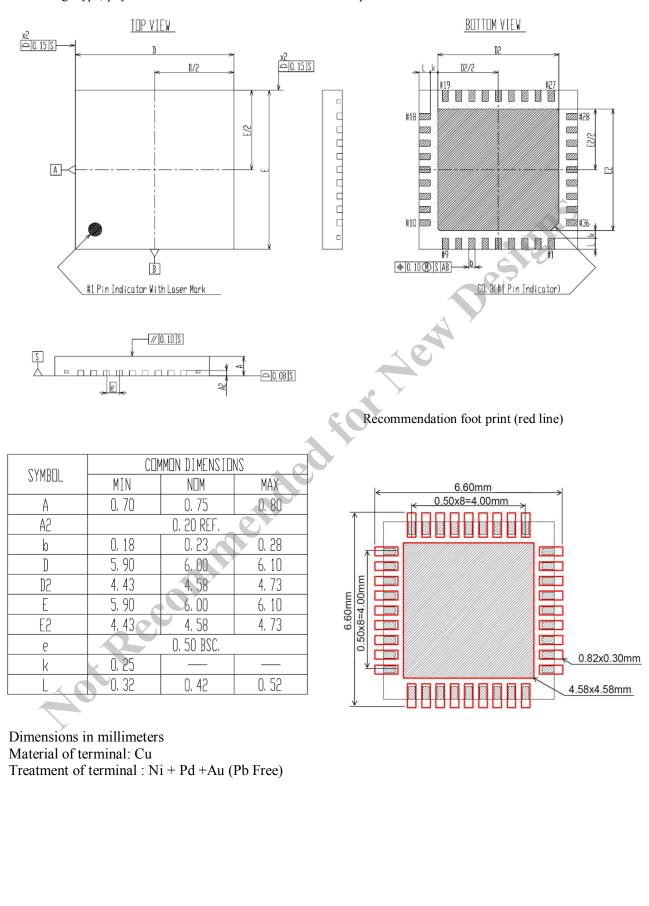
 $\stackrel{\scriptstyle <}{\succ}$ Precaution to avoid the noise on V_{DD} line.

Switching noise from PCB traces, where high current flows, to the V_{DD} line should be minimized because the noise level more than 0.3Von the V_{DD} line may cause malfunctioning operation.

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7 Package information

7-1 Package type, physical dimensions and recommendation foot print



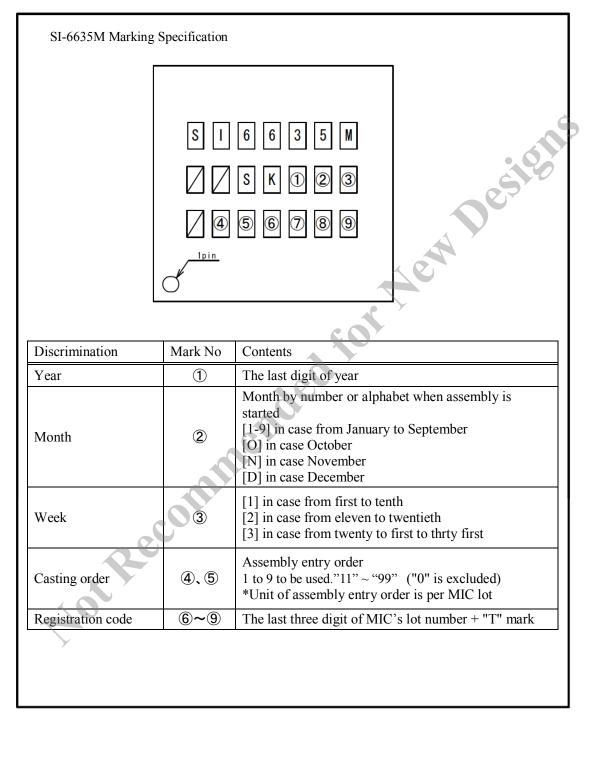
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7-2 Appearance

The body shall be clean and shall not bear any stain, rust or flaw.

7-3 Marking

The type number and lot number shall be clearly marked by laser so that cannot be erased easily. 7-4 Blanding



8 Packing specifications

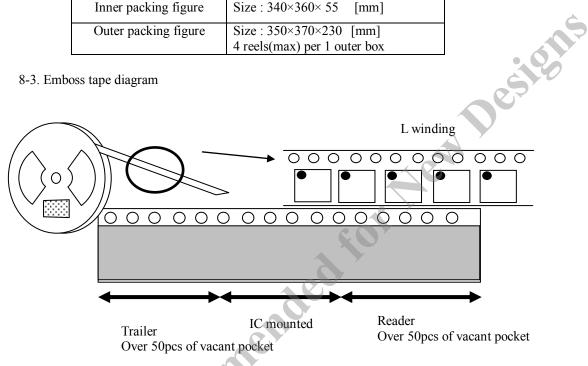
8-1. Container/Material/The number of parts per reel

Container is taping. the number of parts is 2500pcs per reel. Remainder is packed with combination with next lot.

8-2. The material of taping

Material	
Emboss tape	The width of tape : 16mm
Reel	φ330 [mm]
laminate bag	Size : 0.075×380× 450 [mm]
Inner packing figure	Size : 340×360× 55 [mm]
Outer packing figure	Size : 350×370×230 [mm]
	4 reels(max) per 1 outer box

8-3. Emboss tape diagram

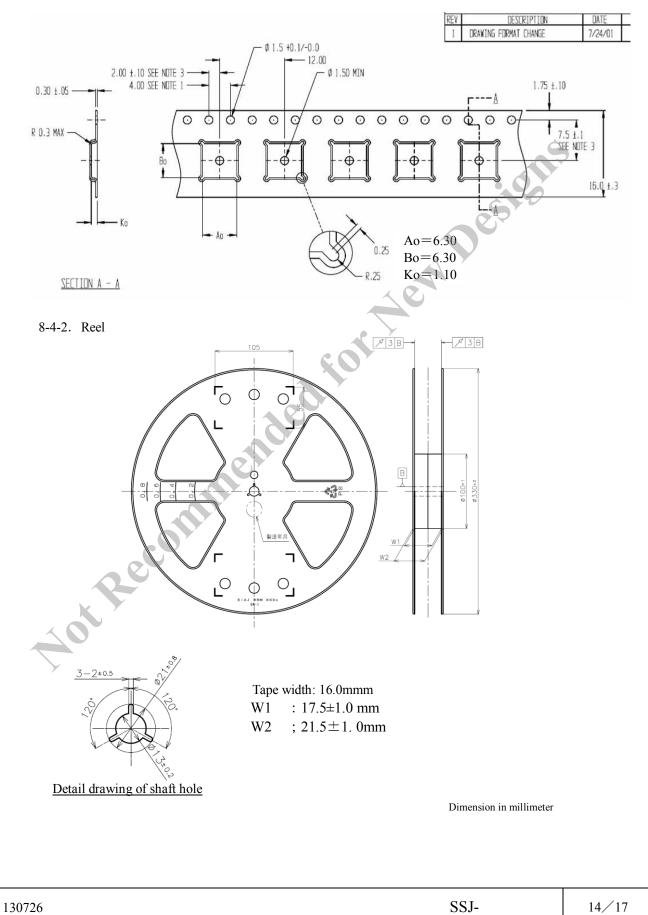


* It is heat-sealed with cover tape in reader and trailer. AotRecor

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8-4. Dimension, material and diagram

8-4-1. Emboss tape



• 8-5-1

Srage environment is below. Temperature: 5 degrees-30 degrees Humidity: 90% or below Storage limitation is within 12month from packing date

8-5-2

If the above storage condition (8-5.1) is expired, the device is needed to have baking with 125 dgerees for 20 hours. Also, Tape and reel are not guaranteed with the temperature and time condition. If the device should be baked, it is needed to use container with "heatproof" or temperture to cover baking Aot Recommended for New Desires condition. And the container is needed to have static electricity control.

9 Cautions and warnings

Input/output (SDA, SCL, FG, FLAG, Brake, ADRS1, ADRS2, TEST)

- Be sure to prevent the logic inout (SDA, SCL, for 2-wire serial) from being "OPEN".
 ※In case some of the logic inputs stay "OPEN", a malfunction may occur due to external noises.
- Logic input (Brake, ADRS1, ADRS2) has internal 78k ohm (typ) pull-down resistor. Please take care that current source/sink capacity of external microcontroller if use.
- TEST terminal should be used as open or connected to GND.
- When the open-drain output (FG, FLAG) is not used, be sure to keep it "OPEN" or GND. %In case it is connected to VDD, it may cause the device's deterioration or/and breakdown.

Schottky should be needed between each OUT pin and GND(Please see 6. Example application circuit).

About the protection circuit operation

AotReconnt

This product has protection circuits (motor coil short-circuit and overheating).

These protection circuits work with detecting the thing that excessive energy joins the driver.

Therefore, it is not possible to protect it when the energy caused by the motor coil short-circuit is outside the tolerance of the driver.

Notice

This driver has MOS inputs. Please notice as following contents.

- When static electricity is a problem, care should be taken to properly control the room humidity. This is particularly true in the winter when static electricity is most troublesome.
- Care should be taken with device leads and with assembly sequencing to avoid applying static charges to IC leads. PC board pins should be shorted together to keep them at the same potential to avoid this kind of trouble.

10. other

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